# 74AHC123A; 74AHCT123A

Dual retriggerable monostable multivibrator with reset

Rev. 5 — 17 June 2020

Product data sheet

### 1. General description

The 74AHC123A; 74AHCT123A is a dual retriggerable monostable multivibrator with reset. The basic output pulse width is programmed by selection of external components ( $R_{EXT}$  and  $C_{EXT}$ ). Once triggered this basic pulse width may be extended by retriggering either of the edge triggered inputs ( $n\overline{A}$  or (nB). By repeating this process, the output pulse period (nQ = HIGH,  $n\overline{Q} = LOW$ ) can be made as long as desired. Alternatively, an output delay can be terminated at any time by a LOW-going edge on input  $n\overline{R}D$ . Inputs are overvoltage tolerant. This feature allows the use of these devices as translators in mixed voltage environments.

#### 2. Features and benefits

- Wide supply voltage range from 2.0 V to 5.5 V
- DC triggered from active HIGH or active LOW inputs
- Retriggerable for very long pulses up to 100 % duty factor
- · Direct reset terminates output pulse
- Overvoltage tolerant inputs to 5.5 V
- All inputs have a Schmitt-trigger action
- · High noise immunity
- Input levels:
  - For 74AHC123A: CMOS level
  - For 74AHCT123A: TTL level
- ESD protection:
  - HBM JESD22-A114E exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V
  - CDM JESD22-C101C exceeds 1000 V
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level A
- Multiple package options
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

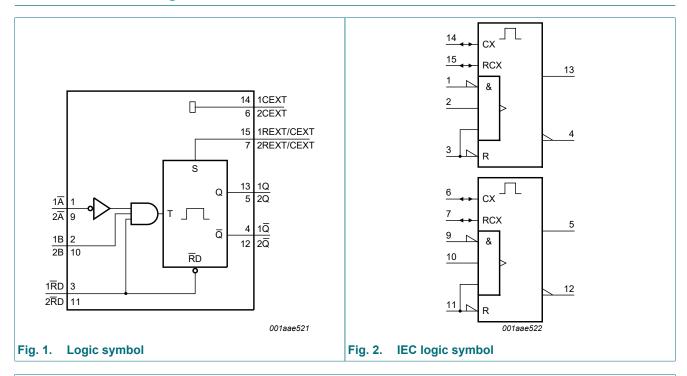
# 3. Ordering information

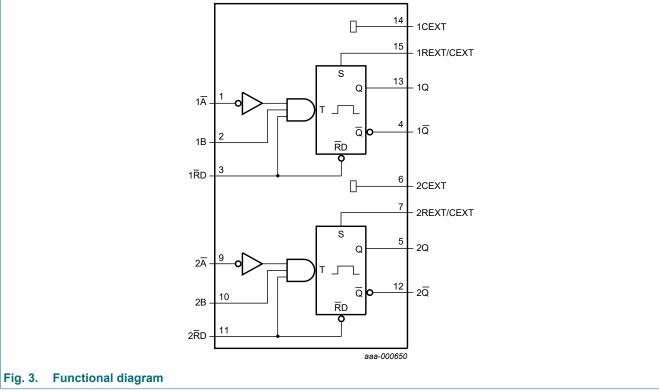
**Table 1. Ordering information** 

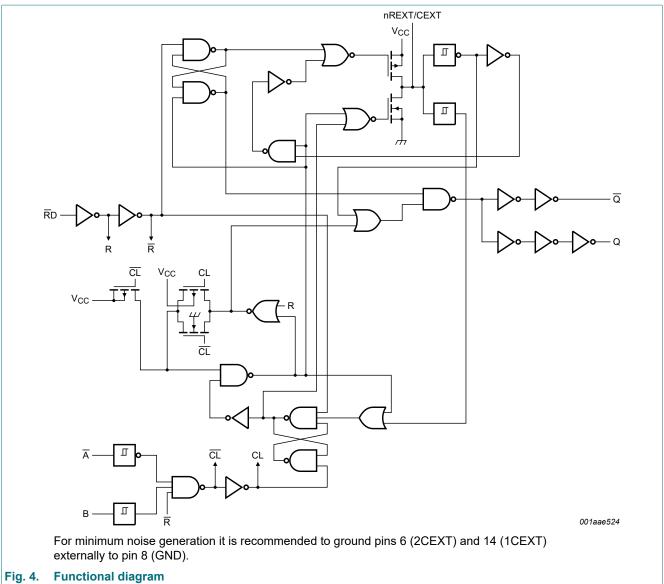
Type number	Package			
	Temperature range	Name	Description	Version
74AHC123AD	-40 °C to +125 °C	SO16	plastic small outline package; 16 leads;	SOT109-1
74AHCT123AD			body width 3.9 mm	
74AHC123APW	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads;	SOT403-1
74AHCT123APW			body width 4.4 mm	
74AHC123ABQ	-40 °C to +125 °C	DHVQFN16	plastic dual in-line compatible thermal enhanced	SOT763-1
74AHCT123ABQ			very thin quad flat package; no leads; 16 terminals; body 2.5 × 3.5 × 0.85 mm	



# 4. Functional diagram

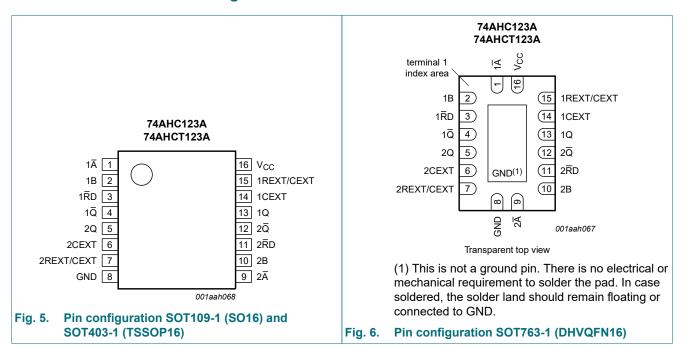






# 5. Pinning information

### 5.1. Pinning



### 5.2. Pin description

Table 2. Pin description

Symbol	Pin	Description
1Ā	1	negative-edge triggered input 1
1B	2	positive-edge triggered input 1
1RD	3	direct reset LOW and positive-edge triggered input 1
1Q	4	active LOW output 1
2Q	5	active HIGH output 2
2CEXT	6	external capacitor connection 2
2REXT/CEXT	7	external resistor and capacitor connection 2
GND	8	ground (0 V)
2 <del>A</del>	9	negative-edge triggered input 2
2B	10	positive-edge triggered input 2
2RD	11	direct reset LOW and positive-edge triggered input 2
2Q	12	active LOW output 2
1Q	13	active HIGH output 1
1CEXT	14	external capacitor connection 1
1REXT/CEXT	15	external resistor and capacitor connection 1
V <sub>CC</sub>	16	supply voltage

# 6. Functional description

#### Table 3. Function table

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level; \ X = don't \ care;$ 

↑ = LOW-to-HIGH transition;

 $\Pi$  = one HIGH level output pulse;

I = one LOW level output pulse.

Input			Output					
nRD	nĀ	nB	nQ	nQ				
L	Х	X	L	Н				
X	Н	X	L [1]	H [1]				
X	Х	L	L [1]	H [1]				
Н	L	1	Л	П				
Н	<b>↓</b>	Н	Л	П				
1	L	Н	Л	П				

<sup>[1]</sup> If the monostable multivibrator was triggered before this condition was established, the pulse will continue as programmed.

# 7. Limiting values

#### **Table 4. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC}$	supply voltage		-0.5	+7.0	V
VI	input voltage		-0.5	+7.0	V
I <sub>IK</sub>	input clamping current	$V_{I} < -0.5 \text{ V}$ [1]	-20	-	mA
I <sub>OK</sub>	output clamping current	$V_O < -0.5 \text{ V or } V_O > V_{CC} + 0.5 \text{ V}$ [1]	-	±20	mA
Io	output current	$V_{O} = -0.5 \text{ V to } (V_{CC} + 0.5 \text{ V})$	-	±25	mA
I <sub>CC</sub>	supply current		-	75	mA
I <sub>GND</sub>	ground current		-75	-	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40  ^{\circ}\text{C} \text{ to } +125  ^{\circ}\text{C}$ [2]	-	500	mW

<sup>1]</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

For SOT403-1 (TSSOP16) package: Ptot derates linearly with 8.5 mW/K above 91 °C.

For SOT763-1 (DHVQFN16) package: Ptot derates linearly with 11.2 mW/K above 106 °C.

<sup>[2]</sup> For SOT109-1 (SO16) package: P<sub>tot</sub> derates linearly with 12.4 mW/K above 110 °C.

# 8. Recommended operating conditions

#### Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	7-	4AHC123	BA	74	Unit		
			Min	Тур	Max	Min	Тур	Max	
V <sub>CC</sub>	supply voltage		2.0	5.0	5.5	4.5	5.0	5.5	V
VI	input voltage		0	-	5.5	0	-	5.5	V
Vo	output voltage		0	-	V <sub>CC</sub>	0	-	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	+25	+125	-40	+25	+125	°C
Δt/ΔV	input transition rise and	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$	-	-	100	-	-	-	ns/V
	fall rate	$V_{CC} = 5.0 \text{ V} \pm 0.5 \text{ V}$	-	-	20	-	-	20	ns/V

# 9. Static characteristics

#### **Table 6. Static characteristics**

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C			°C to 5 °C	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
74AHC1	23A		<u> </u>					'		
V <sub>IH</sub>	HIGH-level	V <sub>CC</sub> = 2.0 V	1.5	-	-	1.5	-	1.5	-	V
	input voltage	V <sub>CC</sub> = 3.0 V	2.1	-	-	2.1	-	2.1	-	V
		V <sub>CC</sub> = 5.5 V	3.85	-	-	3.85	-	3.85	-	V
V <sub>IL</sub>	LOW-level	V <sub>CC</sub> = 2.0 V	-	-	0.5	-	0.5	-	0.5	V
	input voltage	V <sub>CC</sub> = 3.0 V	-	-	0.9	-	0.9	-	0.9	V
		V <sub>CC</sub> = 5.5 V	-	-	1.65	-	1.65	-	1.65	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>								
		I <sub>O</sub> = -50 μA; V <sub>CC</sub> = 2.0 V	1.9	2.0	-	1.9	-	1.9	-	V
		I <sub>O</sub> = -50 μA; V <sub>CC</sub> = 3.0 V	2.9	3.0	-	2.9	-	2.9	-	V
		I <sub>O</sub> = -50 μA; V <sub>CC</sub> = 4.5 V	4.4	4.5	-	4.4	-	4.4	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V	2.58	-	-	2.48	-	2.40	-	V
		I <sub>O</sub> = -8.0 mA; V <sub>CC</sub> = 4.5 V	3.94	-	-	3.8	-	3.70	-	V
V <sub>OL</sub>	LOW-level	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>								
	output voltage	I <sub>O</sub> = 50 μA; V <sub>CC</sub> = 2.0 V	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 50 μA; V <sub>CC</sub> = 3.0 V	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 50 μA; V <sub>CC</sub> = 4.5 V	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.36	-	0.44	-	0.55	V
		I <sub>O</sub> = 8.0 mA; V <sub>CC</sub> = 4.5 V	-	-	0.36	-	0.44	-	0.55	V

Symbol	Parameter	Conditions		25 °	C		°C to 5 °C		°C to 25 °C	Unit
			Mi	1 Тур	Max	Min	Max	Min	Max	
l <sub>l</sub>	input leakage current	V <sub>I</sub> = 5.5 V or GND; V <sub>CC</sub> = 0 V to 5.5 V								
		nREXT/CEXT	[1] -	-	±0.25	-	±2.5	-	±10.0	μΑ
		pins nĀ, nB, nRD	-	-	±0.1	-	±1.0	-	±2.0	μΑ
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$	-	-	4.0	-	40	-	80	μA
		active state (per circuit); V <sub>I</sub> = V <sub>CC</sub> or GND	[1]							
		V <sub>CC</sub> = 3.0 V	-	160	250	-	280	-	280	μΑ
		V <sub>CC</sub> = 4.5 V	-	380	500	-	650	-	650	μΑ
		V <sub>CC</sub> = 5.5 V	-	560	750	-	975	-	975	μΑ
Cı	input capacitance		-	5.0	10	-	10	-	10	pF
Co	output capacitance		-	4.0	-	-	-	-	-	pF
74AHCT	123A	1								
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	2.0	-	-	2.0	-	2.0	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	-	-	0.8	-	0.8	-	0.8	V
V <sub>OH</sub>	HIGH-level	$V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	I <sub>O</sub> = -50 μA	4.4	4.5	-	4.4	-	4.4	-	V
		I <sub>O</sub> = -8.0 mA	3.9	4 -	-	3.8	-	3.70	-	V
V <sub>OL</sub>	LOW-level	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>CC</sub> = 4.5 V								
	output voltage	I <sub>O</sub> = 50 μA	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 8.0 mA	-	-	0.36	-	0.44	-	0.55	V
I <sub>I</sub>	input leakage current	nREXT/CEXT; V <sub>I</sub> = 5.5 V or GND; V <sub>CC</sub> = 0 V to 5.5 V	[1] -	-	±0.25	-	±2.5	-	±10.0	μА
		pins n $\overline{A}$ , nB, n $\overline{R}D$ ; V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 5.5 V	-	-	±0.1	-	±1.0	-	±2.0	μΑ
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$	-	-	4.0	-	40	-	80	μΑ
		active state (per circuit); V <sub>I</sub> = V <sub>CC</sub> or GND	[1]							
		V <sub>CC</sub> = 4.5 V	-	380	500	-	650	-	650	μΑ
		V <sub>CC</sub> = 5.5 V	-	560	750	-	975	-	975	μΑ
C <sub>I</sub>	input capacitance		-	3	10	-	10	-	10	pF
Co	output capacitance		-	4.0	-	-	-	-	-	pF

<sup>[1]</sup> Voltage on nREXT/CEXT =  $0.5 \times V_{CC}$  and pin nREXT/CEXT in OFF-state during test.

# 10. Dynamic characteristics

#### **Table 7. Dynamic characteristics**

GND = 0 V; For test circuit see Fig. 12.

Symbol	Parameter	Conditions		25 °C			°C to 5 °C	-40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	
74AHC1	23A									
t <sub>pd</sub>	propagation									
	delay	V <sub>CC</sub> = 3.0 V to 3.6 V; C <sub>L</sub> = 15 pF	-	7.4	20.6	1.0	24.0	1.0	26.0	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V; C <sub>L</sub> = 50 pF	-	10.5	24.1	1.0	27.5	1.0	30.0	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V; C <sub>L</sub> = 15 pF	-	5.1	12.0	1.0	14.0	1.0	15.5	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V; C <sub>L</sub> = 50 pF	-	7.3	14.0	1.0	16.0	1.0	17.5	ns
		$\overline{nRD}$ to $\overline{nQ}$ and $\overline{nQ}$ ; see $\overline{\underline{Fig. 7}}$ [2]								
		V <sub>CC</sub> = 3.0 V to 3.6 V; C <sub>L</sub> = 15 pF	-	8.2	22.4	1.0	26.0	1.0	28.0	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V; C <sub>L</sub> = 50 pF	-	11.7	25.9	1.0	29.5	1.0	32.0	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V; C <sub>L</sub> = 15 pF	-	5.6	12.9	1.0	15.0	1.0	16.5	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V; C <sub>L</sub> = 50 pF	-	8.1	14.9	1.0	17.0	1.0	19.0	ns
		$\overline{nRD}$ to $\overline{nQ}$ and $\overline{nQ}$ (reset); see Fig. 7 [2]								
		V <sub>CC</sub> = 3.0 V to 3.6 V; C <sub>L</sub> = 15 pF	-	6.4	15.8	1.0	18.5	1.0	20.0	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V; C <sub>L</sub> = 50 pF	-	9.2	19.3	1.0	22.0	1.0	24.5	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V; C <sub>L</sub> = 15 pF	-	4.4	9.4	1.0	11.0	1.0	12.0	ns
		$V_{CC}$ = 4.5 V to 5.5 V; $C_L$ = 50 pF	-	6.3	11.4	1.0	13.0	1.0	14.5	ns
t <sub>W</sub>	pulse width	inputs; nA = LOW; see Fig. 7								
		V <sub>CC</sub> = 3.0 V to 3.6 V	5.0	-	-	5.0	-	5.0	-	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V	5.0	-	-	5.0	-	5.0	-	ns
		inputs; nB = HIGH; see Fig. 7								
		V <sub>CC</sub> = 3.0 V to 3.6 V	5.0	-	-	5.0	-	5.0	-	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V	5.0	-	-	5.0	-	5.0	-	ns
		inputs; nRD = LOW; see Fig. 7								
		V <sub>CC</sub> = 3.0 V to 3.6 V	5.0	-	-	5.0	-	5.0	-	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V	5.0	-	-	5.0	-	5.0	-	ns
		outputs; $n\overline{Q}$ = LOW and [3] $nQ$ = HIGH; $C_L$ = 50 pF; see Fig. 7, Fig. 8, Fig. 9 and Fig. 10								
		$C_{EXT}$ = 28 pF; $R_{EXT}$ = 2 k $\Omega$								
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	115	240	-	300	-	300	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V	-	100	200	-	240	-	240	ns
		$C_{EXT} = 0.01  \mu F;  R_{EXT} = 10  k\Omega$								
		V <sub>CC</sub> = 3.0 V to 3.6 V	90	100	110	90	110	85	115	μs
		V <sub>CC</sub> = 4.5 V to 5.5 V	90	100	110	90	110	85	115	μs
		$C_{EXT} = 0.1  \mu F;  R_{EXT} = 10  k\Omega;$								
		V <sub>CC</sub> = 3.0 V to 3.6 V	0.9	1	1.1	0.9	1.1	0.85	1.15	ms
		V <sub>CC</sub> = 4.5 V to 5.5 V	0.9	1	1.1	0.9	1.1	0.85	1.15	ms

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Symbol	Parameter	Conditions		25 °C			°C to 5 °C		°C to 5 °C	Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	
t <sub>rtrig</sub>	retrigger time	$n\overline{A}$ to nB; $C_{EXT}$ = 100 pF; $R_{EXT}$ = 1 k $\Omega$ ; $C_L$ = 50 pF; see <u>Fig. 8</u> and <u>Fig. 10</u>								
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	60	-	-	-	-	-	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V	-	39	-	-	-	-	-	ns
		$n\overline{A}$ to nB; $C_{EXT}$ = 0.01 μF; $R_{EXT}$ = 1 kΩ; $C_L$ = 50 pF; see <u>Fig. 8</u> and <u>Fig. 10</u>								
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	1.5	-	-	-	-	-	μs
		V <sub>CC</sub> = 4.5 V to 5.5 V	-	1.2	-	-	-	-	-	μs
C <sub>PD</sub>	power dissipation capacitance	$C_L = 50 \text{ pF}; f_i = 1 \text{ MHz};$ [4] $V_I = \text{GND to } V_{CC}$	-	57	-	-	-	-	-	pF
74AHCT	123A	1								
t <sub>pd</sub>	propagation	$n\overline{A}$ and $nB$ to $nQ$ and $n\overline{Q}$ ; see Fig. 7 [2]								
'	delay	V <sub>CC</sub> = 4.5 V to 5.5 V; C <sub>L</sub> = 15 pF	-	5.0	12.0	1.0	14.0	1.0	15.5	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V; C <sub>L</sub> = 50 pF	-	7.1	14.0	1.0	16.0	1.0	17.5	ns
		$\overline{nRD}$ to $\overline{nQ}$ and $\overline{nQ}$ ; see $\overline{Fig. 7}$ [2]								
		V <sub>CC</sub> = 4.5 V to 5.5 V; C <sub>L</sub> = 15 pF	-	5.2	12.9	1.0	15.0	1.0	16.5	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V; C <sub>L</sub> = 50 pF	-	7.5	14.9	1.0	17.0	1.0	18.5	ns
		$\overline{nRD}$ to $\overline{nQ}$ and $\overline{nQ}$ (reset); see Fig. 7 [2]								+
		V <sub>CC</sub> = 4.5 V to 5.5 V; C <sub>L</sub> = 15 pF	-	4.7	9.4	1.0	11.0	1.0	12.0	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V; C <sub>L</sub> = 50 pF	-	6.7	11.4	1.0	13.0	1.0	14.5	ns
t <sub>W</sub>	pulse width	inputs; nA = LOW; C <sub>L</sub> = 50 pF; see Fig. 7								
		V <sub>CC</sub> = 4.5 V to 5.5 V	5.0	-	-	5.0	-	5.0	-	ns
		inputs; nB = HIGH; C <sub>L</sub> = 50 pF; see <u>Fig. 7</u>								
		V <sub>CC</sub> = 4.5 V to 5.5 V	5.0	-	-	5.0	-	5.0	-	ns
		inputs; nRD = LOW; C <sub>L</sub> = 50 pF; see Fig. 7								
		V <sub>CC</sub> = 4.5 V to 5.5 V	5.0	-	-	5.0	-	5.0	-	ns
		outputs; $n\overline{Q}$ = LOW and $q$ = HIGH; $q$ = 50 pF; $q$ = 2 k $q$ = 2 k $q$ = 2 k $q$ = 3 see Fig. 7, Fig. 8, Fig. 9 and Fig. 10								
		V <sub>CC</sub> = 4.5 V to 5.5 V	-	100	200	-	240	-	240	ns
		$C_{EXT} = 0.01 \ \mu F; \ R_{EXT} = 10 \ k\Omega$								
		V <sub>CC</sub> = 4.5 V to 5.5 V	90	100	110	90	110	85	115	μs
		$C_{EXT} = 0.1 \mu F; R_{EXT} = 10 k\Omega$								
		V <sub>CC</sub> = 4.5 V to 5.5 V	0.9	1	1.1	0.9	1.1	0.85	1.15	ms

Symbol	Parameter	Conditions		25 °C			-40 °C to +85 °C		-40 °C to +125 °C	
			Min	Typ[1]	Max	Min	Max	Min	Max	
t <sub>rtrig</sub>	retrigger time	$n\overline{A}$ to nB; $C_{EXT}$ = 100 pF; $R_{EXT}$ = 1 k $\Omega$ ; $C_L$ = 50 pF; see Fig. 8 and Fig. 10								
		V <sub>CC</sub> = 4.5 V to 5.5 V	-	60	-	-	-	-	-	ns
		$n\overline{A}$ to nB; $C_{EXT}$ = 0.01 μF; $R_{EXT}$ = 1 kΩ; $C_L$ = 50 pF; see Fig. 8 and Fig. 10								
		V <sub>CC</sub> = 4.5 V to 5.5 V	-	1.5	-	-	-	-	-	μs
C <sub>PD</sub>	power dissipation capacitance	$C_L$ = 50 pF; $f_i$ = 1 MHz; [4] $V_I$ = GND to $V_{CC}$	-	58	-	-	-	-	-	pF
External	components									'
R <sub>EXT</sub>	external	V <sub>CC</sub> = 2.0 V	5	-	-	-	-	-	-	kΩ
	resistance	V <sub>CC</sub> > 3.0 V	1	-	-	-	-	-	-	kΩ
C <sub>EXT</sub>	external	V <sub>CC</sub> = 2.0 V [5]	-	-	-	-	-	-	-	pF
	capacitance	V <sub>CC</sub> > 3.0 V [5]	-	-	-	-	-	-	-	pF

- Typical values are measured at nominal supply voltage ( $V_{CC}$  = 3.3 V and  $V_{CC}$  = 5.0 V).
- [2] t<sub>pd</sub> is the same as t<sub>PLH</sub> and t<sub>PHL</sub>; C<sub>EXT</sub> = 0 pF; R<sub>EXT</sub> = 5 kΩ.
   [3] For C<sub>EXT</sub> ≥ 10 nF the typical value of the pulse width t<sub>W</sub> (μs) = C<sub>EXT</sub> (nF) × R<sub>EXT</sub> (kΩ).
   [4] C<sub>PD</sub> is used to determine the dynamic power dissipation P<sub>D</sub> (μW).
   P<sub>D</sub> = C<sub>PD</sub> × V<sub>CC</sub><sup>2</sup> × f<sub>i</sub> + Σ(C<sub>L</sub> × V<sub>CC</sub><sup>2</sup> × f<sub>o</sub>) where:

$$P_D = C_{PD} \times V_{CC}^2 \times f_i + \Sigma (C_L \times V_{CC}^2 \times f_o)$$
 where:

f<sub>i</sub> = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

C<sub>L</sub> = output load capacitance in pF;

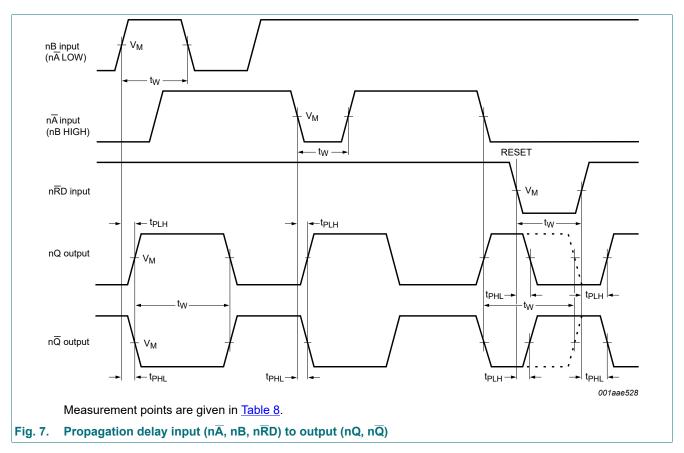
V<sub>CC</sub> = supply voltage in V.

[5] C<sub>EXT</sub> has no limits.

**Product data sheet** 

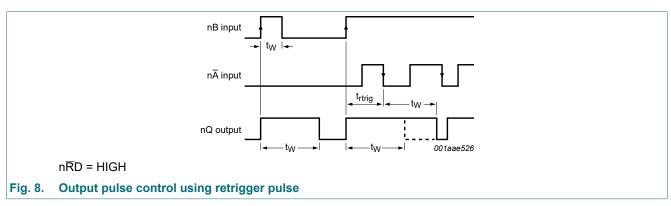
10 / 19

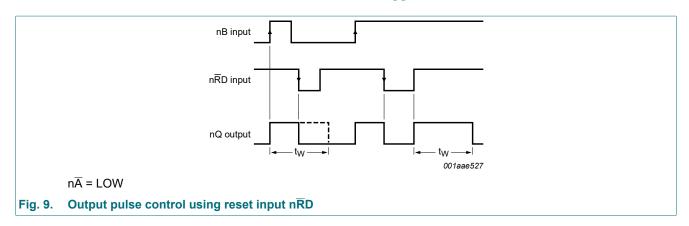
### 10.1. Waveforms

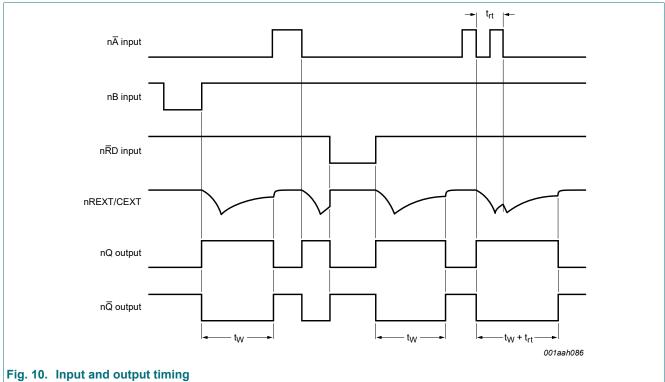


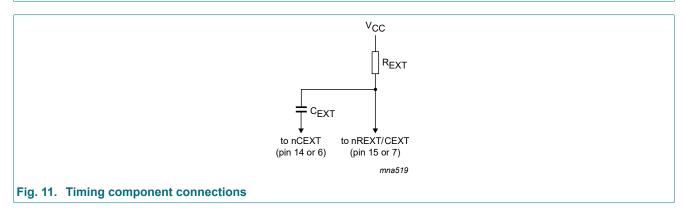
**Table 8. Measurement points** 

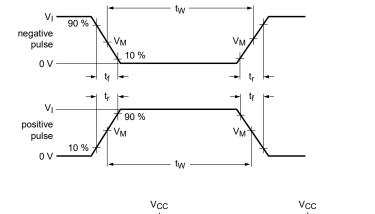
Туре	Input	Output
	V <sub>M</sub>	V <sub>M</sub>
74AHC123A	0.5V <sub>CC</sub>	0.5V <sub>CC</sub>
74AHCT123A	1.5 V	0.5V <sub>CC</sub>

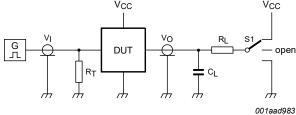












Test data is given in Table 9.

Definitions test circuit:

 $R_T$  = Termination resistance should be equal to output impedance  $Z_o$  of the pulse generator

C<sub>L</sub> = Load capacitance including jig and probe capacitance

R<sub>I</sub> = Load resistance

S1 = Test selection switch

Fig. 12. Test circuit for measuring switching times

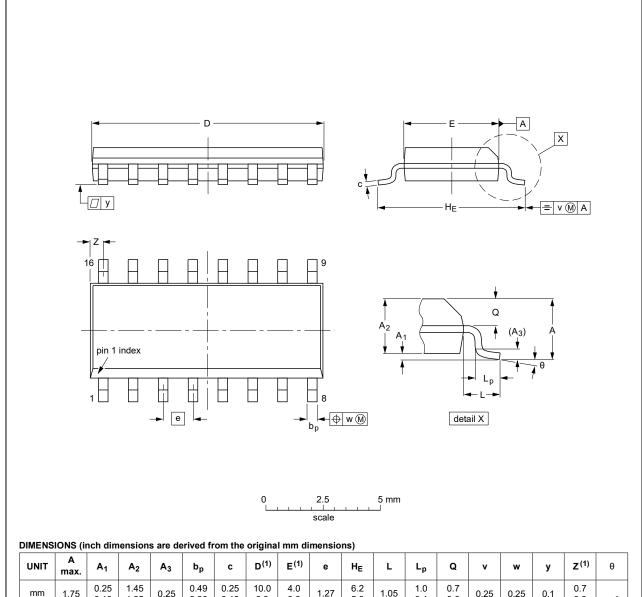
Table 9. Test data

Туре	Input		Load		S1 position		
	V <sub>I</sub>	t <sub>r</sub> , t <sub>f</sub>	CL	R <sub>L</sub> t <sub>i</sub>		t <sub>PZH</sub> , t <sub>PHZ</sub>	t <sub>PZL</sub> , t <sub>PLZ</sub>
74AHC123A	V <sub>CC</sub>	3.0 ns	15 pF, 50 pF	1 kΩ	open	GND	V <sub>CC</sub>
74AHCT123A	3.0 V	3.0 ns	15 pF, 50 pF	1 kΩ	open	GND	V <sub>CC</sub>

# 11. Package outline



SOT109-1



UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	bp	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	10.0 9.8	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.010 0.004	0.057 0.049	0.01		0.0100 0.0075	0.39 0.38	0.16 0.15	0.05	0.244 0.228	0.041	0.039 0.016	0.028 0.020	0.01	0.01	0.004	0.028 0.012	0°

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	1330E DATE	
SOT109-1	076E07	MS-012				<del>99-12-27</del> 03-02-19	

Fig. 13. Package outline SOT109-1 (SO16)

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1

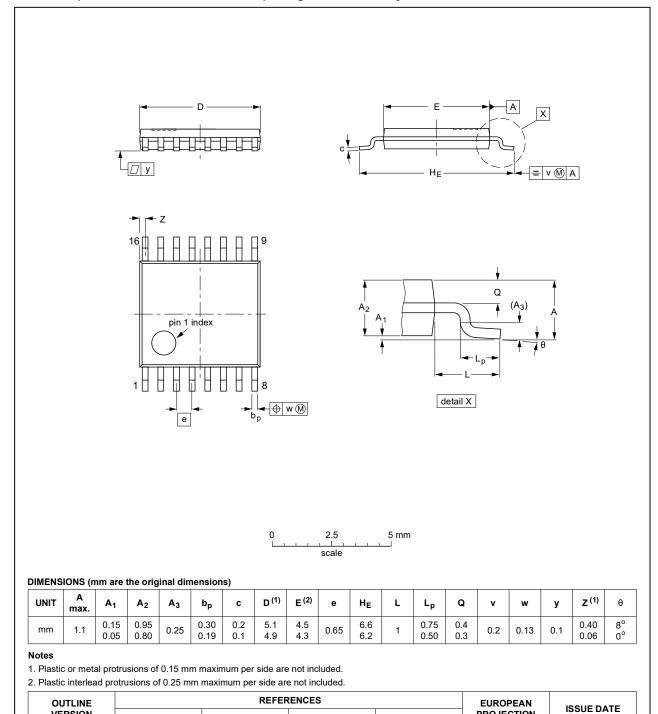


Fig. 14. Package outline SOT403-1 (TSSOP16)

IEC

**JEDEC** 

MO-153

VERSION

SOT403-1

JEITA

99-12-27

03-02-18

**PROJECTION** 

DHVQFN16: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 x 3.5 x 0.85 mm SOT763-1

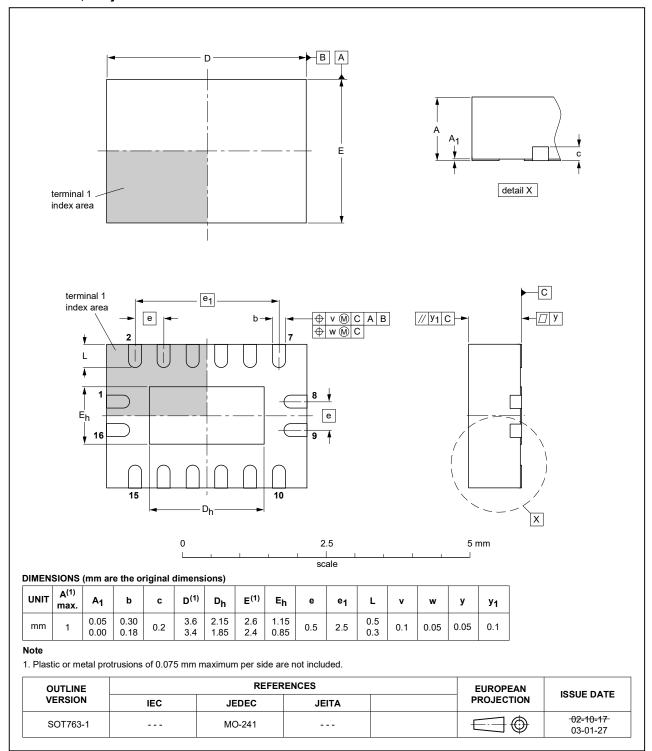


Fig. 15. Package outline SOT763-1 (DHVQFN16)

# 12. Abbreviations

#### **Table 10. Abbreviations**

Table 1017 to blot lations					
Acronym	Description				
CDM	Charged-Device Model				
CMOS	Complementary Metal Oxide Semiconductor				
DUT	Device Under Test				
ESD	ElectroStatic Discharge				
НВМ	Human Body Model				
MM	Machine Model				
TTL	Transistor-Transistor Logic				

# 13. Revision history

#### Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
74AHC_AHCT123A v.5	20200617	Product data sheet	-	74AHC_AHCT123A v.4	
Modifications:	guidelines of Legal texts  Section 1 a	of this data sheet has beer of Nexperia. have been adapted to the nd <u>Section 2</u> updated. rating values for P <sub>tot</sub> total p	new company nar	ne where appropriate.	
74AHC_AHCT123A v.4	20111108	Product data sheet	-	74AHC_AHCT123A v.3	
Modifications:	Legal page:	s updated.			
74AHC_AHCT123A v.3	20110908	Product data sheet	-	74AHC_AHCT123A v.2	
74AHC_AHCT123A v.2	20080118	Product data sheet	-	74AHC_AHCT123A v.1	
74AHC_AHCT123A v.1	20000315	Product specification	-	-	

### 14. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition			
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.			
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.			
Product [short] data sheet	Production	This document contains the product specification.			

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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